

HM6716 Series HM6719 Series

Maintenance Only

2048-word × 8-bit High Speed Hi-BiCMOS Static RAM (with $\overline{OE}$)
2048-word × 9-bit High Speed Hi-BiCMOS Static RAM (with $\overline{OE}$)

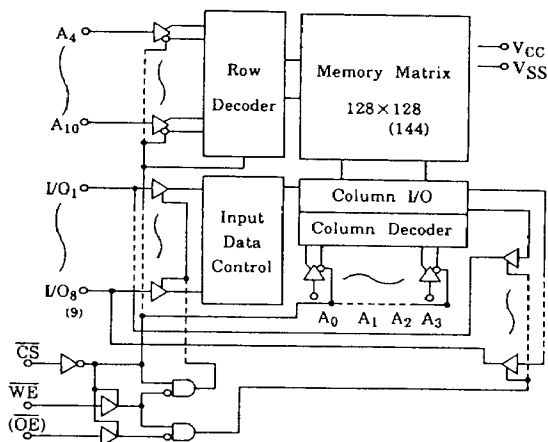
■ Features

- Fast Access Time: 25/30ns (max)
- Low Power Dissipation (DC): 280mW (typ.)
- +5V Single Supply
- Completely Static Memory No Clock or Timing Strobe Required
- Balanced Read and Write Cycle Time
- Fully TTL Compatible Input and Output

■ ORDERING INFORMATION

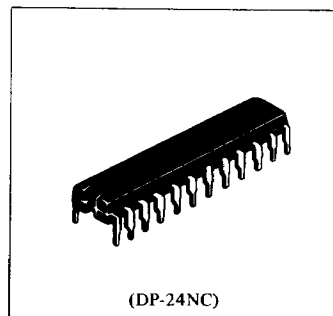
Type No.	Access Time	Package
HM6716P-25	25ns	300 mil 24 Pin Plastic DIP
HM6716P-30	30ns	
HM6719P-25	25ns	
HM6719P-30	30ns	

■ Block Diagram



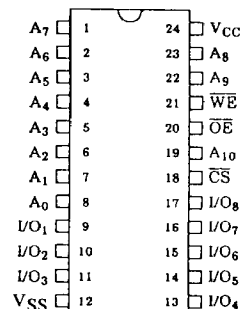
■ Absolute Maximum Ratings

Item	Symbol	Rating	Unit
Terminal Voltage to VSS Pin	V_T	-0.5 to +7.0	V
Power Dissipation	P_T	1.0	W
Operating Temperature Range	T_{opr}	0 to +70	°C
Storage Temperature Range	T_{stg}	-55 to +125	°C



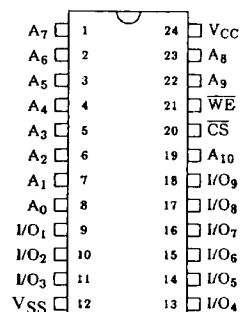
■ PIN ARRANGEMENT

● HM6716



(Top View)

● HM6719



(Top View)



■ Truth Table

● HM6716

$\overline{CS}$	$\overline{OE}$	$\overline{WE}$	Mode	V_{CC} Current	Pin	Ref. Cycle
H	H or L	H or L	Not selected	I_{SB}, I_{SB1}	High Z	—
L	L	H	Read	I_{CC}, I_{CC1}	Dout	Read Cycle (1) (2) (3)
L	H	L	Write	I_{CC}, I_{CC1}	Din	Write Cycle (1)
L	L	L	Write	I_{CC}, I_{CC1}	Din	Write Cycle (2)
L	H	H	Output Disabled	I_{CC}, I_{CC1}	High Z	—

● HM6719

$\overline{CS}$	$\overline{WE}$	Mode	V_{CC} Current	I/O Pin	Ref. Cycle
H	H or L	Not selected	I_{SB}, I_{SB1}	High Z	—
L	H	Read	I_{CC}, I_{CC1}	Dout	Read Cycle (2) (3)
L	L	Write	I_{CC}, I_{CC1}	Din	Write Cycle (2)

■ Recommended DC Operating Conditions ($T_a = 0$ to $+70^\circ\text{C}$)

Item	Symbol	min	typ	max	Unit
Supply Voltage	V_{CC}	4.5	5.0	5.5	V
	V_{SS}	0.0	0.0	0.0	V
Input High Voltage	V_{IH}	2.2	—	6.0	V
Input Low Voltage	$V_{IL}^{*)}$	-3.0	—	0.8	V

*) Pulse Width: 20ns, DC: -0.5V

■ DC and Operating Characteristics ($V_{CC} = 5V \pm 10\%$, $T_a = 0$ to $+70^\circ\text{C}$)

Item	Symbol	Test Conditions	min	typ	max	Unit
Input Leakage Current	$ I_{LI} $	$V_{CC}=5.5V, V_{IN}=V_{SS}$ to V_{CC}	—	—	2	μA
Output Leakage Current	$ I_{LO} $	$\overline{CS}=V_{IH}, V_{I/O}=V_{SS}$ to V_{CC}	—	—	2	μA
Operating Power Supply Current	I_{CC}	$\overline{CS}=V_{IL}, I_{I/O}=0\text{mA}$	—	—	120	mA
Average Operating Current	I_{CC1}	Min. Cycle, Duty: 100% $I_{I/O}=0\text{mA}$	—	—	130	mA
Standby Power Supply Current	I_{SB}	$\overline{CS}=V_{IH}$	—	—	30	mA
	I_{SB1}	$\overline{CS} \geq V_{CC}-0.2V$ $V_{IN} \leq 0.2V$ or $V_{IN} \geq V_{CC}-0.2V$	—	—	10	mA
Output Low Voltage	V_{OL}	$I_{OL}=4\text{mA}$	—	—	0.4	V
Output High Voltage	V_{OH}	$I_{OH}=-1\text{mA}$	2.4	—	—	V

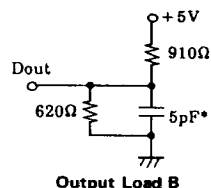
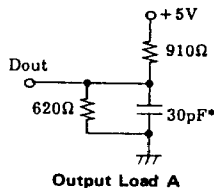
■ AC Test Conditions

Input pulse levels: V_{SS} to 3.0V

Input and Output reference levels: 1.5V

Input rise and fall time: 4ns

Output Load: See Figure



*including scope and jig

 $(t_{CHZ}, t_{WHZ}, t_{CLZ}, t_{OLZ}, t_{OHZ})$ 

■ Capacitance ($T_a = 25^\circ\text{C}$, $f = 1.0\text{ MHz}$)

Item	Symbol	Test Conditions	min	typ	max	Unit
Input Capacitance	C_{IN}	$V_{IN}=0\text{V}$	—	—	6	pF
I/O Capacitance	$C_{I/O}$	$V_{I/O}=0\text{V}$	—	—	8	pF

Note) This parameter is sampled and not 100%, tested.

■ AC Characteristics ($V_{CC} 5\text{V} \pm 10\%$, $T_a = 0$ to $+70^\circ\text{C}$, unless otherwise noted.)

● Read Cycle

Item	Symbol	HM6716-25 HM6719-25		HM6716-30 HM6719-30		Unit	Notes
		min	max	min	max		
Read Cycle Time	t_{RC}	25	—	30	—	ns	—
Address Access Time	t_{AA}	—	25	—	30	ns	—
Chip Select Access Time	t_{ACS}	—	25	—	30	ns	—
Chip Selection to Output in Low Z	t_{CLZ}	0	—	0	—	ns	*2
Output Enable to Output Valid	t_{OE}	0	20	0	20	ns	*1
Output Enable to Output in Low Z	t_{OLZ}	0	—	0	—	ns	*1, *2
Chip Deselection to Output in High Z	t_{CHZ}	0	10	0	12	ns	*2
Chip Disable to Output in High Z	t_{OHZ}	0	10	0	10	ns	*1, *2
Output Hold from Address Change	t_{OH}	5	—	5	—	ns	—
Input Voltage Rise/Fall Time	t_T	—	150	—	150	ns	*3

● Write Cycle

Item	Symbol	HM6716-25 HM6719-25		HM6716-30 HM6719-30		Unit	Notes
		min	max	min	max		
Write Cycle Time	t_{WC}	25	—	30	—	ns	—
Chip Selection to End of Write	t_{CW}	20	—	25	—	ns	—
Address Setup Time	t_{AS}	0	—	0	—	ns	—
Address Valid to End of Write	t_{AW}	20	—	25	—	ns	—
Write Pulse Width	t_{WP}	20	—	25	—	ns	—
Write Recovery Time	t_{WR}	0	—	0	—	ns	—
Output Disable to Output in High Z	t_{OHZ}	0	10	0	10	ns	*1, *2
Write to Output in High Z	t_{WHZ}	0	10	0	12	ns	*2
Data Valid to End of Write	t_{DW}	15	—	15	—	ns	—
Data Hold Time	t_{DH}	5	—	5	—	ns	—
Output Active from End of Write	t_{OW}	0	—	0	—	ns	*2

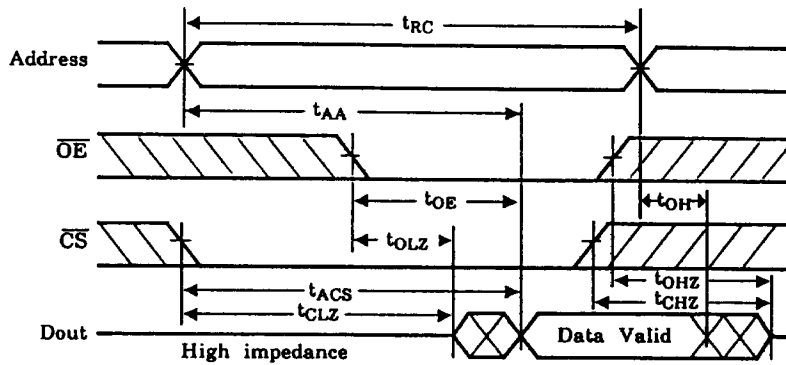
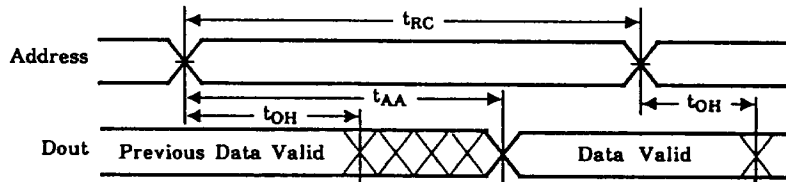
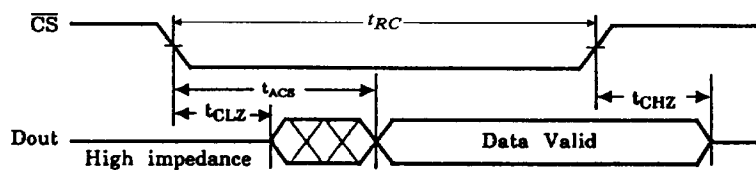
Notes) *1. These parameters are for HM6716.

*2. Transition is measured $\pm 200\text{mV}$ from steady state voltage with Load(B).
This parameter is sampled and not 100% tested.

*3. If t_T becomes more than 150ns, there is possibility of function fail.
Please contact your nearest Hitachi's Sale Dept. regarding specification.



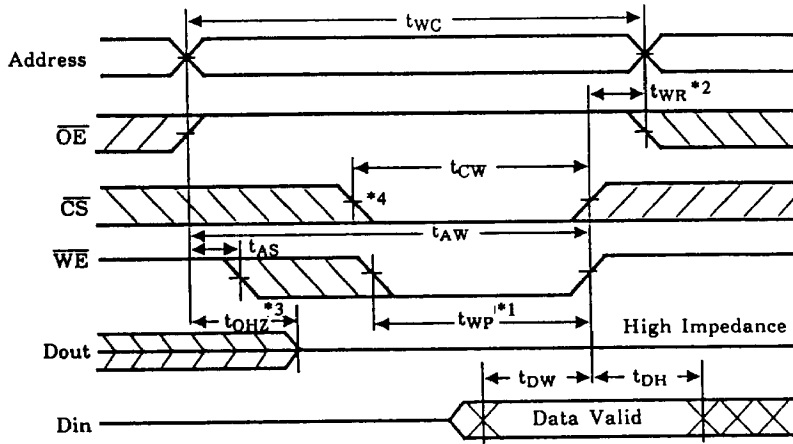
■ Timing Waveforms

● Read Cycle (1)^{*1}● Read Cycle (2)^{*1,*2,*4}● Read Cycle (3)^{*1,*3,*4}

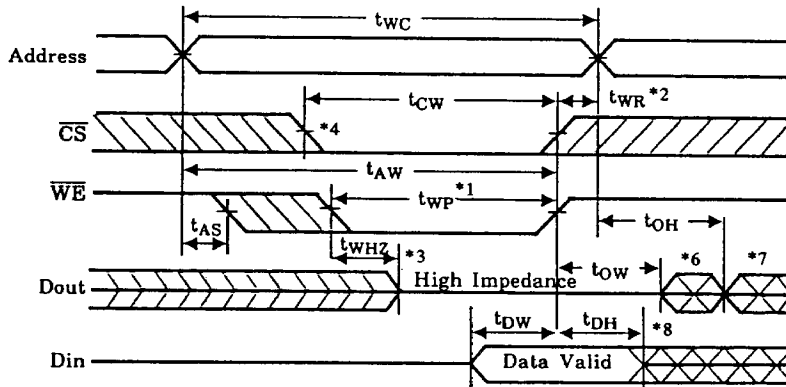
- Notes) *1. $\overline{WE}$ is High for Read Cycle.
 *2. Device is continuously selected, $\overline{CS}=V_{IL}$.
 *3. Address Valid prior to or coincident with CS transition Low.
 *4. $\overline{OE}=V_{IL}$.



• Write Cycle (1)



• Write Cycle (2)^{*5}



- Notes) *1. A write occurs during the overlap (t_{WP}) of a low $\overline{CS}$ and low $\overline{WE}$.
 *2. t_{WR} is measured from the earlier of $\overline{CS}$ or $\overline{WE}$ going high to the end of write cycle.
 *3. During this period, I/O pins are in the output state so that the input signals of opposite phase to the outputs must not be applied.
 *4. If the $\overline{CS}$ low transition occurs simultaneously with the $\overline{WE}$ low transitions or after the $\overline{WE}$ transition, output remain in a high impedance state.
 *5. $\overline{OE}$ is continuously low. ($\overline{OE} = V_{LL}$).
 *6. D_{out} is the same phase of write data of this write cycle.
 *7. D_{out} is the read data of next address.
 *8. If $\overline{CS}$ is Low during this period, I/O pins are in the output state. Then the data input signals of opposite phase to the outputs must not be applied to them.

